

Initial Data & Reliability Test Comparison Data of DLW43SH series

添付資料
Appendix

弊社品番 / Murata Part No.: DLW43SH101XK2

現行工場 / Current Factory : 登米村田製作所/Tome Murata Mfg. Co., Ltd.

新工場 / New Factory : Murata Electronics (Malaysia) Sdn.Bhd.

試験項目、条件 Testing Item, Condition	サンプル数 Sample Size	評価項目 Confirmed Item	Tome/Japan		Malaysia	判定値 Acceptance Value	判定 OK/NG
			現行工場 Current Factory	新工場 New Factory			
1. 初期値/Initial	30	L寸法/Dimension L(mm)	AVG	4.563	4.566	4.5±0.2 mm	OK
			MAX	4.58	4.58		
			MIN	4.55	4.55		
			σ	0.006	0.005		
		W寸法/Dimension W(mm)	AVG	3.227	3.240	3.2±0.2 mm	OK
			MAX	3.26	3.26		
			MIN	3.21	3.22		
			σ	0.011	0.011		
		T寸法/Dimension T(mm)	AVG	2.541	2.538	2.6±0.2 mm	OK
			MAX	2.56	2.55		
			MIN	2.53	2.49		
			σ	0.008	0.011		
	共通インダクタンス/ Common Mode Inductance(Lc) (μH) at 1MHz	AVG	108.47	106.29	100μH -30%/+50%	OK	
		MAX	116.7	114.0			
		MIN	97.6	98.1			
		σ	5.068	3.864			
	絶縁抵抗/ Insulation Resistance(MΩ)	AVG	7.58E+11	7.71E+11	1.0E+07Ω MIN.	OK	
		MAX	1.3E+12	9.9E+11			
MIN		3.4E+10	5.1E+11				
σ		-	-				
耐電圧/Withstand Voltage(V) 125DCV		No damaged	No damaged	No damaged	OK		
直流抵抗/ DC Resistance [Rdc] (mΩ)	AVG	1.062	1.052	2.0Ω MAX.	OK		
	MAX	1.19	1.07				
	MIN	1.04	1.03				
	σ	0.0348	0.0088				
2. 電極固着力/ Bending Strength 荷重/Force : 17.7N 保持時間/Hold Duration : 60seconds	30	外観/Appearance		No damaged	No damaged	No damaged	OK
3. たわみ強度/ Bending Strength 基板材質/Substrate : Glass-epoxy substrate (t=1.6mm). たわみ量/Deflection: 2mm 保持時間/Hold Duration: 60 seconds 加圧治具/Pressure jig : R230	30	外観/Appearance		No damaged	No damaged	No damaged	OK
		共通インダクタンス/ Common Mode Inductance(Lc) (μH) at 1MHz	AVG	110.65	108.88	100μH -30%/+50%	OK
			MAX	115.2	115.0		
			MIN	102.8	101.1		
		絶縁抵抗/ Insulation Resistance(MΩ)	AVG	2.22E+11	6.53E+11	1.0E+07Ω MIN.	OK
			MAX	7.5E+11	8.5E+11		
			MIN	2.8E+10	4.8E+11		
耐電圧/Withstand Voltage(V) 125DCV		No damaged	No damaged	No damaged	OK		
4. 落下試験/ Drop 落下方法/ Method: free fall 落下高さ/Height: 1m 落下回数/ The number of Times: 10 times	30	外観/Appearance		No damaged	No damaged	No damaged	OK
		共通インダクタンス/ Common Mode Inductance(Lc) (μH) at 1MHz	AVG	102.72	107.59	100μH -30%/+50%	OK
			MAX	110.8	114.6		
			MIN	93.2	100.5		
		絶縁抵抗/ Insulation Resistance(MΩ)	AVG	1.03E+12	6.84E+11	1.0E+07Ω MIN.	OK
			MAX	1.2E+12	9.3E+11		
			MIN	7.2E+11	1.3E+11		
耐電圧/Withstand Voltage(V) 125DCV		No damaged	No damaged	No damaged	OK		
5. 耐振性/Vibration 振動周波数/Oscillation Frequency : 10Hz to 2000Hz to 10Hz for 20 min. 加速度幅/Total Amplitude : 3.0mm or Acceleration amplitude 245m/s ² whichever is smaller. 試験時間/Testing Time : A period of 2h in each of 3 mutually perpendicular directions	30	外観/Appearance		No damaged	No damaged	No damaged	OK
		共通インダクタンス/ Common Mode Inductance(Lc) (μH) at 1MHz	AVG	112.17	109.77	100μH -30%/+50%	OK
			MAX	119.2	119.2		
			MIN	106.4	101.2		
		絶縁抵抗/ Insulation Resistance(MΩ)	AVG	6.29E+11	5.81E+11	1.0E+07Ω MIN.	OK
			MAX	8.6E+11	9.7E+11		
			MIN	2.2E+11	1.8E+11		
耐電圧/Withstand Voltage(V) 125DCV		No damaged	No damaged	No damaged	OK		

試験項目、条件 Testing Item, Condition	サンプル数 Sample Size	評価項目 Confirmed Item		現行工場 Current Factory	新工場 New Factory	判定値 Acceptance Value	判定 OK/NG
6. はんだ付け性/Solderability フラックス/Flux : Ethanol solution of rosin,25(wt)% 予熱/Pre-Heating : 150±5°C/60±5s はんだ/Solder : Sn-3.0Ag-0.5Cu はんだ温度/Solder Temperature : 245±3°C 浸せき時間/Immersion Time : 4±1s 浸せき引上げ速度/Immersion and Emersion rates : 25mm/s	30	濡れ面積/ New uniform coating area		>90%	>90%	90%	OK
7. はんだ耐熱/Resistance to Soldering Heat 予熱/Pre-Heating : 150±5°C/60±5s はんだ/Solder : Sn-3.0Ag-0.5Cu はんだ温度/Solder Temperature : 260±5°C 浸せき時間/Immersion Time : 10±0.5s 浸せき引上げ速度/Immersion and Emersion rates : 25mm/s	30	外観/Appearance		No damaged	No damaged	No damaged	OK
		共通インダクタンス/ Common Mode Inductance(Lc) (μ H) at 1MHz	AVG	113.55	107.47	100 μ H -30%/+50%	OK
			MAX	119.9	116.8		
			MIN	103.0	91.2		
		絶縁抵抗/ Insulation Resistance(M Ω)	AVG	5.70E+11	5.70E+11	1.0E+07 Ω MIN.	OK
			MAX	1.8E+12	1.8E+12		
MIN	5.8E+10		5.8E+10				
耐電圧/Withstand Voltage(V) 125DCV		No damaged	No damaged	No damaged	OK		
8. 温度サイクル/Temperature Cycle 1サイクル条件/1 Cycle condition Step 1: -40°C+0/-3°C, 30±3 min. Step 2: 125°C+3/-0°C, 30±3 min. 回数/Total of Cycles :1000 cycles	77	外観/Appearance		No damaged	No damaged	No damaged	OK
		共通インダクタンス/ Common Mode Inductance(Lc) (μ H) at 1MHz	AVG	115.22	108.48	100 μ H -30%/+50%	OK
			MAX	125.1	118.7		
			MIN	99.3	90.0		
		絶縁抵抗/ Insulation Resistance(M Ω)	AVG	1.46E+12	1.30E+12	1.0E+07 Ω MIN.	OK
			MAX	4.5E+12	3.2E+12		
MIN	8.7E+11		5.4E+10				
耐電圧/Withstand Voltage(V) 125DCV		No damaged	No damaged	No damaged	OK		
9. 耐湿性/Humidity 温度/Temperature : 85±2°C 湿度/Humidity : 85±5%(RH) 時間/Time : 1000h(+48h,-0h)	77	外観/Appearance		No damaged	No damaged	No damaged	OK
		共通インダクタンス/ Common Mode Inductance(Lc) (μ H) at 1MHz	AVG	112.19	110.64	100 μ H -30%/+50%	OK
			MAX	120.7	121.1		
			MIN	100.7	97.5		
		絶縁抵抗/ Insulation Resistance(M Ω)	AVG	1.36E+12	9.50E+11	1.0E+07 Ω MIN.	OK
			MAX	2.7E+12	2.1E+12		
MIN	2.4E+11		3.9E+10				
耐電圧/Withstand Voltage(V) 125DCV		No damaged	No damaged	No damaged	OK		
10. 高温負荷試験/Heat Life 温度/Temperature : 125±2°C 印加電力/Applying Current: Rated Current 時間/Time : 1000h(+48h,-0h)	77	外観/Appearance		No damaged	No damaged	No damaged	OK
		共通インダクタンス/ Common Mode Inductance(Lc) (μ H) at 1MHz	AVG	113.50	111.77	100 μ H -30%/+50%	OK
			MAX	125.1	125.2		
			MIN	98.3	104.9		
		絶縁抵抗/ Insulation Resistance(M Ω)	AVG	1.12E+12	1.18E+12	1.0E+07 Ω MIN.	OK
			MAX	2.5E+12	7.7E+12		
MIN	3.2E+11		1.2E+11				
耐電圧/Withstand Voltage(V) 125DCV		No damaged	No damaged	No damaged	OK		
11. 耐寒性/Cold Resistance 温度/Temperature : -40±2°C 時間/Time : 1000h(+48h,-0h)	77	外観/Appearance		No damaged	No damaged	No damaged	OK
		共通インダクタンス/ Common Mode Inductance(Lc) (μ H) at 1MHz	AVG	117.20	114.37	100 μ H -30%/+50%	OK
			MAX	131.3	121.3		
			MIN	100.1	102.6		
		絶縁抵抗/ Insulation Resistance(M Ω)	AVG	6.81E+11	1.30E+12	1.0E+07 Ω MIN.	OK
			MAX	2.2E+12	2.5E+12		
MIN	4.7E+10		3.1E+10				
耐電圧/Withstand Voltage(V) 125DCV		No damaged	No damaged	No damaged	OK		